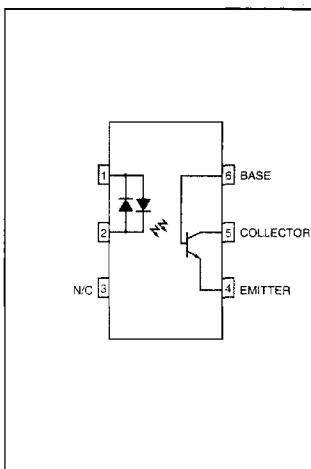
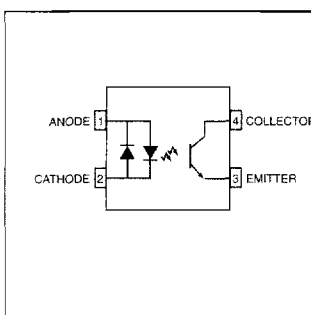




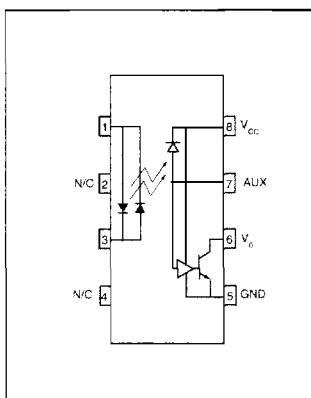
Phototransistor Output, GaAs AC Input

Part Number	CTR @ $\pm 10 \text{ mA } I_F(\%)$		BV_{CEO} (V) min	BV_{CBO} (V) min	$V_{CE(sat)}$ (V) max	t_{ON}/t_{OFF} (μs) max	V_{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
	min	max							
H11AA1	20	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U
H11AA1.300	20	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V
H11AA2	10	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U
H11AA2.300	10	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V
H11AA3	50	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U
H11AA3.300	50	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V
H11AA4	100	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U
H11AA4.300	100	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V



Phototransistor Output, GaAs AC Input (No base connection) (4-Pin)

Part Number	CTR @ $\pm 1 \text{ mA } I_F(\%)$		BV_{CEO} (V) min	BV_{CBO} (V) min	$V_{CE(sat)}$ (V) max	t_{ON}/t_{OFF} (μs) max	V_{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
	min	max							
H11AA814	20	300	35	6	0.2	18	5.3 kV	G	A, U
H11AA814.300	20	300	35	6	0.2	18	5.3 kV	G	A, U, V
H11AA814A	50	150	35	6	0.2	18	5.3 kV	G	A, U
H11AA814A.300	50	150	35	6	0.2	18	5.3 kV	G	A, U, V



Logic Output, GaAs AC Input

Part Number	I _{I(ON)} RMS (mA) min	I _{I(OFF)} RMS (mA) max	V _{CC} (V) max	V _{I (ON)} RMS (V) min	V _{I(OFF)} RMS (V) max	I _{OH} (μA) max	V _{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
MID400	4	0.15	7	90	5.5	100	2.25 kV	D	A, U

Notes

A complete list of agencies appears on page 23.
Optocoupler Package outlines appear on pages 24, 25, and 26.